3. Ordering information

Table 1. Ordering information

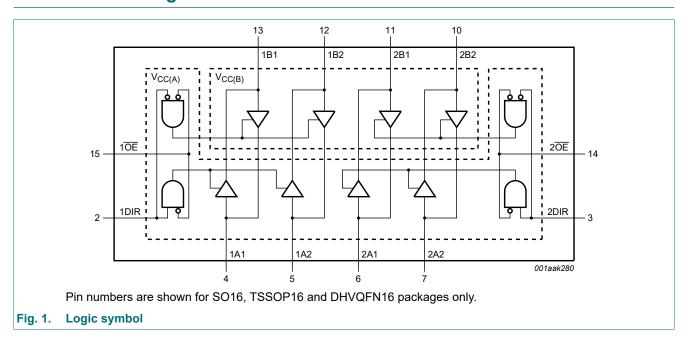
Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AVC4T245D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				
74AVC4T245PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				
74AVC4T245BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1				
74AVC4T245GU-Q100	-40 °C to +125 °C	XQFN16	plastic, extremely thin quad flat package; no leads; 16 terminals; body 1.80 × 2.60 × 0.50 mm	SOT1161-1				

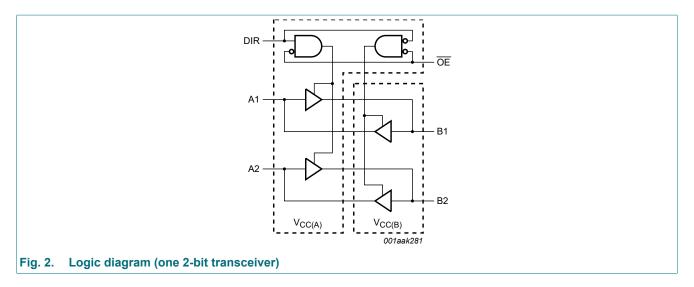
4. Marking

Table 2. Marking codes

Type number	Marking code
74AVC4T245D-Q100	74AVC4T245D
74AVC4T245PW-Q100	VC4T245
74AVC4T245BQ-Q100	C4T245
74AVC4T245GU-Q100	BT5

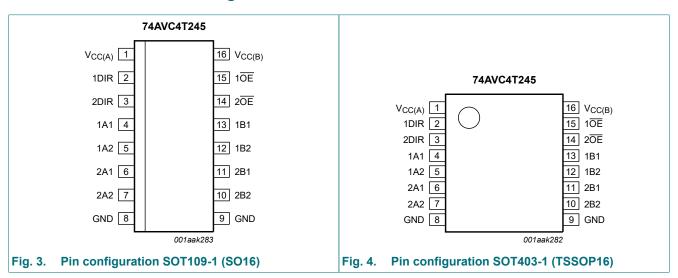
5. Functional diagram

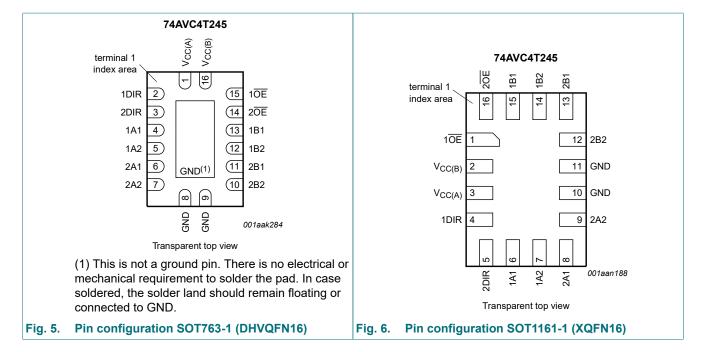




6. Pinning information

6.1. Pinning





6.2. Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT109-1, SOT403-1 and SOT763-1	SOT1161-1	
V _{CC(A)}	1	3	supply voltage A (nAn, nOE and nDIR inputs are referenced to V _{CC(A)})
1DIR, 2DIR	2, 3	4, 5	direction control
1A1, 1A2	4, 5	6, 7	data input or output
2A1, 2A2	6, 7	8, 9	data input or output
GND[1]	8, 9	10, 11	ground (0 V)
2B2, 2B1	10, 11	12, 13	data input or output
1B2, 1B1	12, 13	14, 15	data input or output
2 OE , 1 OE	14, 15	16, 1	output enable input (active LOW)
V _{CC(B)}	16	2	supply voltage B (nBn inputs are referenced to $V_{\text{CC(B)}}$)

[1] All GND pins must be connected to ground (0 V).

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Supply voltage	Input		Input/output[1]		
$V_{CC(A)}, V_{CC(B)}$	nOE[2] nDIR[2] n		nAn[2]	nBn[2]	
0.8 V to 3.6 V	L	L	nAn = nBn	input	
0.8 V to 3.6 V	L	Н	input	nBn = nAn	
0.8 V to 3.6 V	Н	X	Z	Z	
GND[1]	X	Х	Z	Z	

- If at least one of $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into suspend mode. The nAn, nDIR and n \overline{OE} input circuit is referenced to $V_{CC(A)}$; The nBn input circuit is referenced to $V_{CC(B)}$.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC(A)}$	supply voltage A			-0.5	+4.6	V
$V_{CC(B)}$	supply voltage B			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1][2][3]	-0.5	V _{CCO} + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+4.6	V
Io	output current	V _O = 0 V to V _{CCO}	[2]	-	±50	mA
I _{CC}	supply current	per V _{CC(A)} or V _{CC(B)} pin		-	100	mΑ
I _{GND}	ground current	per GND pin		-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		SO16, TSSOP16 and DHVQFN16	[4]	-	500	mW
		XQFN16		-	250	mW

- The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.
- V_{CCO} is the supply voltage associated with the output port.
- V_{CCO} + 0.5 V should not exceed 4.6 V.
- For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: Ptot derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(A)}	supply voltage A			0.8	3.6	V
V _{CC(B)}	supply voltage B			0.8	3.6	V
VI	input voltage			0	3.6	V
Vo	output voltage	Active mode	[1]	0	V _{cco}	V
		Suspend or 3-state mode		0	3.6	V
T _{amb}	ambient temperature			-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CCI} =0.8 V to 3.6 V	[2]	-	5	ns/V

^[1] V_{CCO} is the supply voltage associated with the output port.

10. Static characteristics

Table 7. Typical static characteristics at T_{amb} = 25 °C

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).[1]

Symbol	Parameter	Conditions		Тур	Max	Unit
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = -1.5 mA; V _{CC(A)} = V _{CC(B)} = 0.8 V	-	0.69	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = 1.5 mA; $V_{CC(A)} = V_{CC(B)} = 0.8 \text{ V}$	-	0.07	-	V
I _I	input leakage current	nDIR, n \overline{OE} input; V _I = 0 V or 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V	-	±0.025	±0.25	μΑ
I _{OZ}	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$; [2] $V_{CC(A)} = V_{CC(B)} = 3.6 \text{ V}$	-	±0.5	±2.5	μΑ
		suspend mode A port; $V_O = 0 \text{ V or } V_{CCO}$; [2] $V_{CC(A)} = 3.6 \text{ V}$; $V_{CC(B)} = 0 \text{ V}$	-	±0.5	±2.5	μA
		suspend mode B port; $V_O = 0 \text{ V or } V_{CCO}$; [2] $V_{CC(A)} = 0 \text{ V}$; $V_{CC(B)} = 3.6 \text{ V}$	-	±0.5	±2.5	μΑ
I _{OFF}	power-off leakage current	A port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 0.8$ V to 3.6 V	-	±0.1	±1	μΑ
		B port; V_1 or V_0 = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V; $V_{CC(A)}$ = 0.8 V to 3.6 V	-	±0.1	±1	μΑ
Cı	input capacitance	nDIR, n \overline{OE} input; V _I = 0 V or 3.3 V; V _{CC(A)} = V _{CC(B)} = 3.3 V	-	1.0	-	pF
C _{I/O}	input/output capacitance	A and B port; $V_0 = 3.3 \text{ V or } 0 \text{ V};$ $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$	-	4.0	-	pF

^[1] V_{CCO} is the supply voltage associated with the output port; V_{CCI} is the supply voltage associated with the data input port.

^[2] V_{CCI} is the supply voltage associated with the input port.

^[2] For I/O ports, the parameter I_{OZ} includes the input leakage current.

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).[1]

Symbol	Parameter	Conditions	-40 °C to	o +85 °C	-40 °C to	Unit	
			Min	Max	Min	Max	1
V _{IH}	HIGH-level	data input					
	input voltage	V _{CCI} = 0.8 V	0.70V _{CCI}	-	0.70V _{CCI}	-	V
		V _{CCI} = 1.1 V to 1.95 V	0.65V _{CCI}	-	0.65V _{CCI}	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V _{CCI} = 3.0 V to 3.6 V	2	-	2	-	V
		nDIR, n OE input					
		V _{CC(A)} = 0.8 V	0.70V _{CC(A)}	-	0.70V _{CC(A)}	-	V
		V _{CC(A)} = 1.1 V to 1.95 V	0.65V _{CC(A)}	-	0.65V _{CC(A)}	-	V
		V _{CC(A)} = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V _{CC(A)} = 3.0 V to 3.6 V	2	-	2	-	V
V _{IL}	LOW-level	data input					
	input voltage	V _{CCI} = 0.8 V	-	0.30V _{CCI}	-	0.30V _{CCI}	V
		V _{CCI} = 1.1 V to 1.95 V	-	0.35V _{CCI}	-	0.35V _{CCI}	V
		V _{CCI} = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	-	0.8	-	0.8	V
		nDIR, nOE input					
		V _{CC(A)} = 0.8 V	-	0.30V _{CC(A)}	-	0.30V _{CC(A)}	V
		V _{CC(A)} = 1.1 V to 1.95 V	-	0.35V _{CC(A)}	-	0.35V _{CC(A)}	V
		V _{CC(A)} = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V _{CC(A)} = 3.0 V to 3.6 V	-	0.8	-	0.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}					
	output voltage	I_{O} = -100 μ A; $V_{CC(A)}$ = $V_{CC(B)}$ = 0.8 V to 3.6 V	V _{CCO} - 0.1	-	V _{CCO} - 0.1	-	V
		I _O = -3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V	0.85	-	0.85	-	V
		I _O = -6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V	1.05	-	1.05	-	V
		I_{O} = -8 mA; $V_{CC(A)} = V_{CC(B)} = 1.65 V$	1.2	-	1.2	-	V
		I_{O} = -9 mA; $V_{CC(A)} = V_{CC(B)} = 2.3 V$	1.75	-	1.75	-	V
		I_{O} = -12 mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0 V	2.3	-	2.3	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}					
	output voltage	$I_O = 100 \mu A;$ $V_{CC(A)} = V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	0.1	-	0.1	V
		I _O = 3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V	-	0.25	-	0.25	V
		I _O = 6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V	-	0.35	-	0.35	V
		I _O = 8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V	-	0.45	-	0.45	V
		I _O = 9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V	-	0.55	-	0.55	V
		I _O = 12 mA; V _{CC(A)} = V _{CC(B)} = 3.0 V	-	0.7	-	0.7	V
l _l	input leakage current	nDIR, n \overline{OE} input; V _I = 0 V or 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V	-	±1	-	±5	μΑ

Symbol	Parameter	Conditions	-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	
I _{OZ}	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$; [2] $V_{CC(A)} = V_{CC(B)} = 3.6 \text{ V}$	-	±5	-	±30	μА
		suspend mode A port; [2] $V_O = 0 \text{ V or } V_{CCO}$; $V_{CC(A)} = 3.6 \text{ V}$; $V_{CC(B)} = 0 \text{ V}$	-	±5	-	±30	μА
		suspend mode B port; [2] $V_O = 0 \text{ V or } V_{CC(A)} = 0 \text{ V};$ $V_{CC(B)} = 3.6 \text{ V}$	-	±5	-	±30	μА
I _{OFF}	leakage	A port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 0.8$ V to 3.6 V	-	±5	-	±30	μΑ
current	B port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 0.8$ V to 3.6 V	-	±5	-	±30	μΑ	
I _{CC} supply current	A port; $V_I = 0 \text{ V or } V_{CCI}$; $I_O = 0 \text{ A}$						
		$V_{CC(A)} = 0.8 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	10	-	55	μΑ
		V _{CC(A)} = 1.1 V to 3.6 V; V _{CC(B)} = 1.1 V to 3.6 V	-	8	-	50	μΑ
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-	8	-	50	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V	-2	-	-12	-	μA
		B port; V _I = 0 V or V _{CCI} ; I _O = 0 A					
		$V_{CC(A)} = 0.8 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	10	-	55	μΑ
		$V_{CC(A)} = 1.1 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	8	-	50	μA
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-2	-	-12	-	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V	-	8	-	50	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = 0$ V or V_{CCI} ; $V_{CC(A)} = 0.8$ V to 3.6 V; $V_{CC(B)} = 0.8$ V to 3.6 V	-	20	-	70	μА
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = 0$ V or V_{CCI} ; $V_{CC(A)} = 1.1$ V to 3.6 V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	16	-	65	μΑ

 V_{CCO} is the supply voltage associated with the output port; V_{CCI} is the supply voltage associated with the data input port. For I/O ports, the parameter I_{OZ} includes the input leakage current.

Table 9. Typical total supply current $(I_{CC(A)} + I_{CC(B)})$

V _{CC(A)}	V _{CC(B)}							
	0 V	0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
0 V	0	0.1	0.1	0.1	0.1	0.1	0.1	μΑ
0.8 V	0.1	0.1	0.1	0.1	0.1	0.3	1.6	μΑ
1.2 V	0.1	0.1	0.1	0.1	0.1	0.1	0.8	μΑ
1.5 V	0.1	0.1	0.1	0.1	0.1	0.1	0.4	μΑ
1.8 V	0.1	0.1	0.1	0.1	0.1	0.1	0.2	μΑ
2.5 V	0.1	0.3	0.1	0.1	0.1	0.1	0.1	μΑ
3.3 V	0.1	1.6	0.8	0.4	0.2	0.1	0.1	μΑ

11. Dynamic characteristics

Table 10. Typical power dissipation capacitance at $V_{CC(A)} = V_{CC(B)}$ and $T_{amb} = 25$ °C

Voltages are referenced to GND (ground = 0 V).[1][2]

Symbol	Parameter	Conditions			V _{CC(A)} =	= V _{CC(B)}			Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
C _{PD}	power dissipation	A port: (direction nAn to nBn); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
capacitano	capacitance	A port: (direction nAn to nBn); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		A port: (direction nBn to nAn); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		A port: (direction nBn to nAn); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction nAn to nBn); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		B port: (direction nAn to nBn); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction nBn to nAn); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		B port: (direction nBn to nAn); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$$\begin{split} &\Sigma(C_L \ x \ V_{CC}^{\ 2} \ x \ f_o) = \text{sum of the outputs.} \\ [2] \quad &f_i = 10 \ \text{MHz}; \ V_i = \text{GND to } V_{CC}; \ t_r = t_f = 1 \ \text{ns}; \ C_L = 0 \ \text{pF}; \ R_L = \infty \ \Omega. \end{split}$$

Table 11. Typical dynamic characteristics at $V_{CC(A)}$ = 0.8 V and T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9; for waveforms see Fig. 7 and Fig. 8.[1]

Symbol	Parameter	Conditions		$V_{CC(B)}$					
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t _{pd}	propagation delay	nAn to nBn	14.5	7.3	6.5	6.2	5.9	6.0	ns
		nBn to nAn	14.5	12.7	12.4	12.3	12.1	12.0	ns
t _{dis}	disable time	nOE to nAn	14.3	14.3	14.3	14.3	14.3	14.3	ns
		nOE to nBn	17.0	9.9	9.0	9.4	9.0	9.7	ns
t _{en}	enable time	nOE to nAn	18.2	18.2	18.2	18.2	18.2	18.2	ns
		nOE to nBn	19.2	10.7	9.8	9.6	9.7	10.2	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

Table 12. Typical dynamic characteristics at $V_{CC(B)}$ = 0.8 V and T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9; for waveforms see Fig. 7 and Fig. 8.[1]

Symbol	Parameter	Conditions		V _{CC(A)}							
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V			
t _{pd} propagation dela	propagation delay	nAn to nBn	14.5	12.7	12.4	12.3	12.1	12.0	ns		
		nBn to nAn	14.5	7.3	6.5	6.2	5.9	6.0	ns		
t _{dis}	disable time	nOE to nAn	14.3	5.5	4.1	4.0	3.0	3.5	ns		
		nOE to nBn	17.0	13.8	13.4	13.1	12.9	12.7	ns		
t _{en} ena	enable time	nOE to nAn	18.2	5.6	4.0	3.2	2.4	2.2	ns		
		nOE to nBn	19.2	14.6	14.1	13.9	13.7	13.6	ns		

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

Table 13. Dynamic characteristics for temperature range -40 °C to +85 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9; for waveforms see Fig. 7 and Fig. 8.[1]

Symbol	Parameter	Conditions					Vc	C(B)					Unit
			1.2 V	± 0.1 V	1.5 V	± 0.1 V		0.15 V	2.5 V	± 0.2 V	3.3 V	± 0.3 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V _{CC(A)} =	1.1 V to 1.3 V	-		-			1						
t _{pd}	propagation	nAn to nBn	0.5	9.4	0.5	7.1	0.5	6.2	0.5	5.2	0.5	5.1	ns
	delay	nBn to nAn	0.5	9.4	0.5	8.9	0.5	8.7	0.5	8.4	0.5	8.2	ns
t _{dis}	disable time	n OE to nAn	1.8	10.9	1.8	10.9	1.8	10.9	1.8	10.9	1.8	10.9	ns
		n OE to nBn	1.9	12.4	1.9	9.6	1.9	9.5	1.4	8.1	1.2	9.1	ns
t _{en}	enable time	n OE to nAn	1.4	12.8	1.4	12.8	1.4	12.8	1.4	12.8	1.4	12.8	ns
		nOE to nBn	1.1	13.3	1.1	10.0	1.1	8.9	1.0	7.9	1.0	7.7	ns
V _{CC(A)} =	1.4 V to 1.6 V		,	'	'	'	'	'	l	,	'	1	
t _{pd}	propagation	nAn to nBn	0.3	8.9	0.3	6.3	0.3	5.2	0.3	4.2	0.3	4.2	ns
	delay	nBn to nAn	0.7	7.1	0.7	6.3	0.5	6.0	0.4	5.7	0.3	5.6	ns
t _{dis}	disable time	nOE to nAn	1.8	10.2	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	ns
		n OE to nBn	1.9	11.3	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	ns
t _{en}	t _{en} enable time	n OE to nAn	1.1	9.4	1.4	9.4	1.1	9.4	0.7	9.4	0.4	9.4	ns
		nOE to nBn	1.4	12.1	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	ns
V _{CC(A)} =	1.65 V to 1.95	V				'					'		
t _{pd}	propagation delay	nAn to nBn	0.1	8.7	0.1	6.0	0.1	4.9	0.1	3.9	0.3	3.9	ns
		nBn to nAn	0.6	6.2	0.6	5.3	0.5	4.9	0.3	4.6	0.3	4.5	ns
t _{dis}	disable time	nOE to nAn	1.8	8.6	1.6	8.6	1.8	8.6	1.3	8.6	1.6	8.6	ns
		n OE to nBn	1.7	10.9	1.7	9.9	1.6	8.7	1.2	6.9	1.0	6.9	ns
t _{en}	enable time	nOE to nAn	1.0	7.2	1.0	7.2	1.0	7.2	0.6	7.2	0.4	7.2	ns
		n OE to nBn	1.2	11.7	1.2	9.2	1.0	7.4	0.8	5.3	0.8	4.6	ns
V _{CC(A)} =	2.3 V to 2.7 V											<u>'</u>	
t _{pd}	propagation	nAn to nBn	0.1	8.4	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	ns
	delay	nBn to nAn	0.6	5.2	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	ns
t _{dis}	disable time	n OE to nAn	1.0	6.2	1.0	6.2	1.0	6.2	1.0	6.2	1.0	6.2	ns
		n OE to nBn	1.5	10.4	1.5	8.8	1.3	8.2	1.1	6.2	0.9	5.2	ns
t _{en}	enable time	n OE to nAn	0.7	4.8	0.7	4.8	0.7	4.8	0.6	4.8	0.4	4.8	ns
		n OE to nBn	0.9	11.3	0.9	8.8	0.8	7.0	0.6	4.8	0.6	4.0	ns
V _{CC(A)} =	3.0 V to 3.6 V												
t _{pd}	propagation	nAn to nBn	0.1	8.2	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	ns
	delay	nBn to nAn	0.6	5.1	0.6	4.2	0.4	3.4	0.2	3.0	0.1	2.8	ns
t _{dis}	disable time	nOE to nAn	0.7	5.6	0.7	5.6	0.7	5.6	0.7	5.6	0.7	5.6	ns
		nOE to nBn	1.4	10.2	1.4	9.3	1.2	8.1	1.0	6.4	0.8	6.2	ns
t _{en}	enable time	nOE to nAn	0.6	3.8	0.6	3.8	0.6	3.8	0.6	3.8	0.4	3.8	ns
		n OE to nBn	0.8	11.3	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

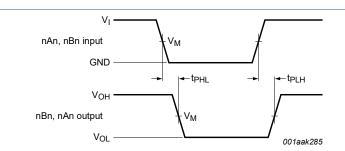
Table 14. Dynamic characteristics for temperature range -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9; for waveforms see Fig. 7 and Fig. 8.[1]

Symbol	Parameter	Conditions					Vc	C(B)					Unit
			1.2 V	± 0.1 V	1.5 V	± 0.1 V	1.8 V ±	0.15 V	2.5 V	± 0.2 V	3.3 V	± 0.3 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V _{CC(A)} =	1.1 V to 1.3 V					'	1	1					
t _{pd}	propagation	nAn to nBn	0.5	10.4	0.5	7.9	0.5	6.9	0.5	5.8	0.5	5.7	ns
	delay	nBn to nAn	0.5	10.4	0.5	9.8	0.5	9.6	0.5	9.3	0.5	9.1	ns
t _{dis}	disable time	n OE to nAn	1.8	12.0	1.8	12.0	1.8	12.0	1.8	12.0	1.8	12.0	ns
		n OE to nBn	1.9	13.7	1.9	10.6	1.9	10.5	1.4	9.0	1.2	10.1	ns
t _{en}	enable time	n OE to nAn	1.4	14.1	1.4	14.1	1.4	14.1	1.4	14.1	1.4	14.1	ns
		nOE to nBn	1.1	14.7	1.1	11.0	1.1	9.8	1.0	8.7	1.0	8.5	ns
V _{CC(A)} =	1.4 V to 1.6 V		'			'	1	1		'	'	'	
t _{pd}	propagation	nAn to nBn	0.3	9.8	0.3	7.0	0.3	5.8	0.3	4.7	0.3	4.7	ns
	delay	nBn to nAn	0.7	7.9	0.7	7.0	0.5	6.6	0.4	6.3	0.3	6.2	ns
t _{dis}	disable time	nOE to nAn	1.8	11.3	1.8	11.3	1.5	11.3	1.3	11.3	1.6	11.3	ns
		nOE to nBn	1.9	12.5	1.9	11.4	1.9	10.1	1.4	8.2	1.2	8.4	ns
t _{en}	enable time	nOE to nAn	1.1	10.4	1.4	10.4	1.1	10.4	0.7	10.4	0.4	10.4	ns
		nOE to nBn	1.4	13.3	1.4	10.6	1.1	8.5	0.9	6.4	0.9	6.2	ns
V _{CC(A)} =	1.65 V to 1.95	V				'	•						
t _{pd}	propagation delay	nAn to nBn	0.1	9.6	0.1	6.6	0.1	5.4	0.1	4.3	0.3	4.3	ns
		nBn to nAn	0.6	6.9	0.6	5.9	0.5	5.4	0.3	5.1	0.3	5.0	ns
t _{dis}	disable time	nOE to nAn	1.8	9.5	1.6	9.5	1.8	9.5	1.3	9.5	1.6	9.5	ns
		nOE to nBn	1.7	12.0	1.7	10.9	1.6	9.6	1.2	7.6	1.0	7.6	ns
t _{en}	enable time	nOE to nAn	1.0	8.0	1.0	8.0	1.0	8.0	0.6	8.0	0.4	8.0	ns
		nOE to nBn	1.2	12.9	1.2	10.2	1.0	8.2	0.8	5.9	0.8	5.1	ns
V _{CC(A)} =	2.3 V to 2.7 V						•						
t _{pd}	propagation	nAn to nBn	0.1	9.3	0.1	6.3	0.1	5.1	0.2	4.0	0.1	4.0	ns
	delay	nBn to nAn	0.6	5.8	0.6	4.7	0.4	4.3	0.2	3.9	0.2	3.8	ns
t _{dis}	disable time	nOE to nAn	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	ns
		nOE to nBn	1.5	11.5	1.5	10.4	1.3	9.1	1.1	6.9	0.9	5.8	ns
t _{en}	enable time	nOE to nAn	0.7	5.3	0.7	5.3	0.7	5.3	0.6	5.3	0.4	5.3	ns
		nOE to nBn	0.9	12.4	0.9	9.7	0.8	7.7	0.6	5.3	0.6	4.4	ns
V _{CC(A)} =	3.0 V to 3.6 V			<u>'</u>	•	'			<u>'</u>				
t _{pd}	propagation	nAn to nBn	0.1	9.1	0.1	6.2	0.1	5.0	0.1	3.8	0.1	3.3	ns
	delay	nBn to nAn	0.6	5.7	0.6	4.7	0.4	3.9	0.2	3.4	0.1	3.3	ns
t _{dis}	disable time	nOE to nAn	0.7	6.2	0.7	6.2	0.7	6.2	0.7	6.2	0.7	6.2	ns
		nOE to nBn	1.4	11.3	1.4	10.3	1.2	9.0	1.0	7.1	0.8	6.9	ns
t _{en}	enable time	nOE to nAn	0.6	4.2	0.6	4.2	0.6	4.2	0.6	4.2	0.4	4.2	ns
		n OE to nBn	0.8	12.4	0.8	9.6	0.6	7.5	0.5	5.2	0.5	4.2	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

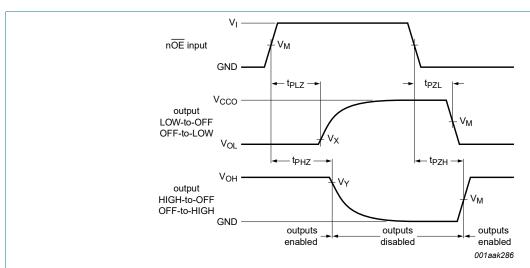
11.1. Waveforms and test circuit



Measurement points are given in Table 15.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 7. The data input (nAn, nBn) to output (nBn, nAn) propagation delay times



Measurement points are given in <u>Table 15</u>.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

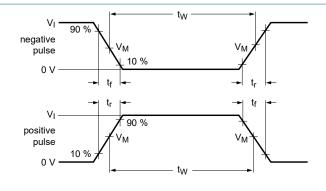
Fig. 8. Enable and disable times

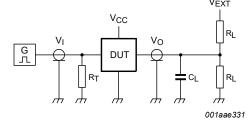
Table 15. Measurement points

Supply voltage	Input[1]	Output[2]	Output[2]					
V _{CC(A)} , V _{CC(B)}	V _M	V _M	V _X	V _Y				
0.8 V to 1.6 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.1 V	V _{OH} - 0.1 V				
1.65 V to 2.7 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} - 0.15 V				
3.0 V to 3.6 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} - 0.3 V				

^[1] V_{CCI} is the supply voltage associated with the data input port.

^[2] V_{CCO} is the supply voltage associated with the output port.





Test data is given in Table 16.

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance.

V_{EXT} = External voltage for measuring switching times.

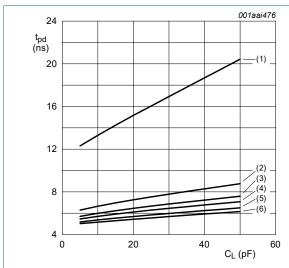
Fig. 9. Test circuit for measuring switching times

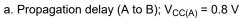
Table 16. Test data

Supply voltage	Supply voltage Input		Load		V _{EXT}			
$V_{CC(A)}, V_{CC(B)}$	V _I [1]	Δt/ΔV [2]	C _L	R_L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} [3]	
0.8 V to 1.6 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}	
1.65 V to 2.7 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}	
3.0 V to 3.6 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}	

- [1] V_{CCI} is the supply voltage associated with the data input port.
- [2] dV/dt ≥ 1.0 V/ns
- [3] V_{CCO} is the supply voltage associated with the output port.

12. Typical propagation delay characteristics





(1)
$$V_{CC(B)} = 0.8 \text{ V}$$

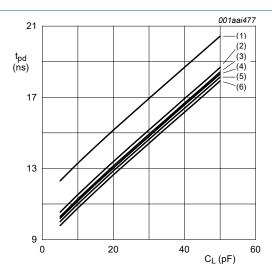
(2)
$$V_{CC(B)} = 1.2 \text{ V}$$

(2)
$$V_{CC(B)} = 1.2 \text{ V}$$

(3) $V_{CC(B)} = 1.5 \text{ V}$
(4) $V_{CC(B)} = 1.8 \text{ V}$
(5) $V_{CC(B)} = 2.5 \text{ V}$
(6) $V_{CC(B)} = 3.3 \text{ V}$

(5)
$$V_{CC(B)} = 2.5 \$$

(6)
$$V_{CC(B)} = 3.3 \text{ V}$$



b. Propagation delay (A to B); $V_{CC(B)} = 0.8 \text{ V}$

(1)
$$V_{CC(A)} = 0.8 \text{ V}$$

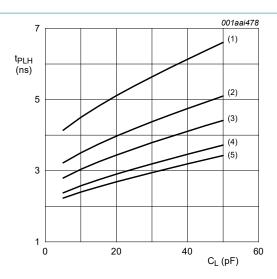
$$\begin{array}{l} \text{(2) V}_{\text{CC}(A)} = 1.2 \text{ V} \\ \text{(3) V}_{\text{CC}(A)} = 1.5 \text{ V} \\ \text{(4) V}_{\text{CC}(A)} = 1.8 \text{ V} \\ \text{(5) V}_{\text{CC}(A)} = 2.5 \text{ V} \\ \text{(6) V}_{\text{CC}(A)} = 3.3 \text{ V} \end{array}$$

(3)
$$V_{CC(A)} = 1.5 \text{ V}$$

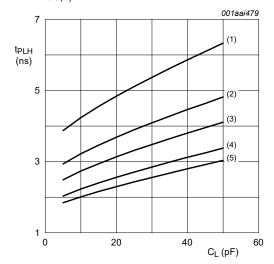
$$(4) V_{CC(A)} = 1.8 V$$

(5)
$$V_{CC(A)} = 2.5 \text{ V}$$

Fig. 10. Typical propagation delay versus load capacitance; T_{amb} = 25 °C

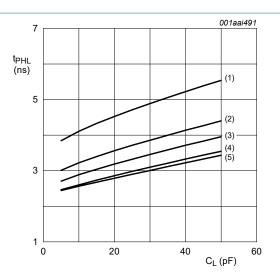


a. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 1.2 \text{ V}$

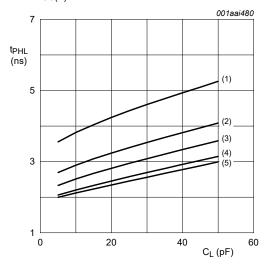


c. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 1.5 \text{ V}$

- (1) $V_{CC(B)} = 1.2 \text{ V}$
- (2) $V_{CC(B)} = 1.5 \text{ V}$
- (3) $V_{CC(B)} = 1.8 \text{ V}$
- (4) $V_{CC(B)} = 2.5 \text{ V}$
- $(5) V_{CC(B)} = 3.3 V$

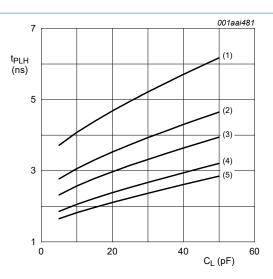


b. HIGH to LOW propagation delay (A to B); $V_{CC(A)} = 1.2 \text{ V}$

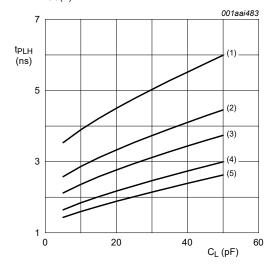


d. HIGH to LOW propagation delay (A to B); $V_{CC(A)} = 1.5 \text{ V}$

Fig. 11. Typical propagation delay versus load capacitance; T_{amb} = 25 °C

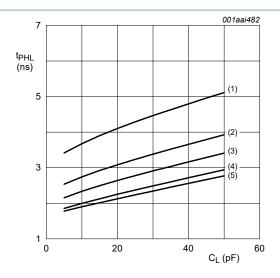


a. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 1.8 \text{ V}$

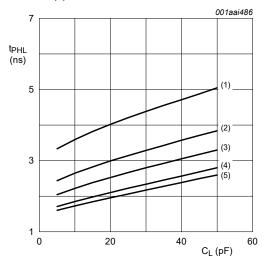


c. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 2.5 \text{ V}$

- (1) $V_{CC(B)} = 1.2 \text{ V}$
- (2) $V_{CC(B)} = 1.5 \text{ V}$
- (3) $V_{CC(B)} = 1.8 \text{ V}$
- (4) $V_{CC(B)} = 2.5 \text{ V}$
- $(5) V_{CC(B)} = 3.3 V$

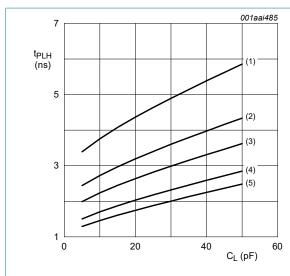


b. HIGH to LOW propagation delay (A to B); $V_{CC(A)} = 1.8 \text{ V}$



d. HIGH to LOW propagation delay (A to B); $V_{CC(A)} = 2.5 \text{ V}$

Fig. 12. Typical propagation delay versus load capacitance; T_{amb} = 25 °C



a. LOW to HIGH propagation delay (A to B);

 $V_{CC(A)} = 3.3 \text{ V}$

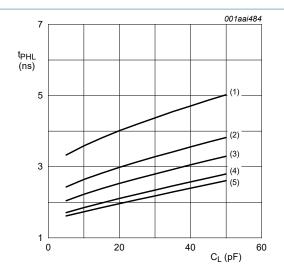
(1) $V_{CC(B)} = 1.2 \text{ V}$

(2) $V_{CC(B)} = 1.5 \text{ V}$

(3) $V_{CC(B)} = 1.8 \text{ V}$

(4) $V_{CC(B)} = 2.5 \text{ V}$

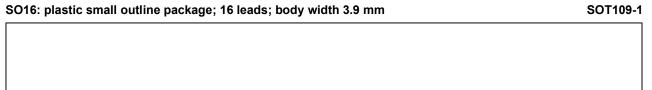
(5) $V_{CC(B)} = 3.3 \text{ V}$

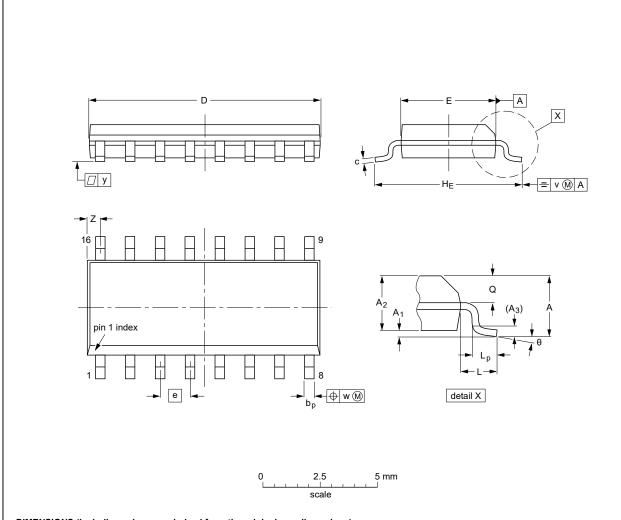


b. HIGH to LOW propagation delay (A to B); $V_{CC(A)} = 3.3 \text{ V}$

Fig. 13. Typical propagation delay versus load capacitance; T_{amb} = 25 °C

13. Package outline





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig. 14. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

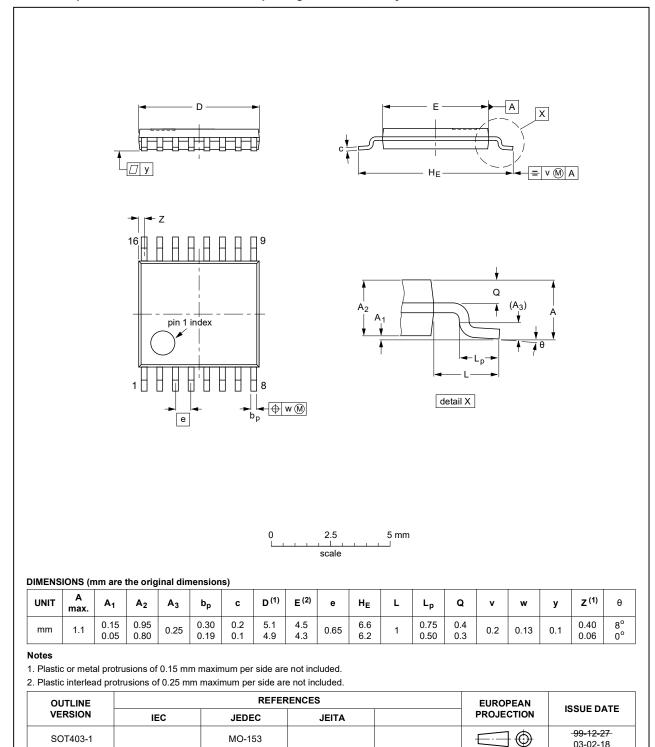


Fig. 15. Package outline SOT403-1 (TSSOP16)

03-02-18

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

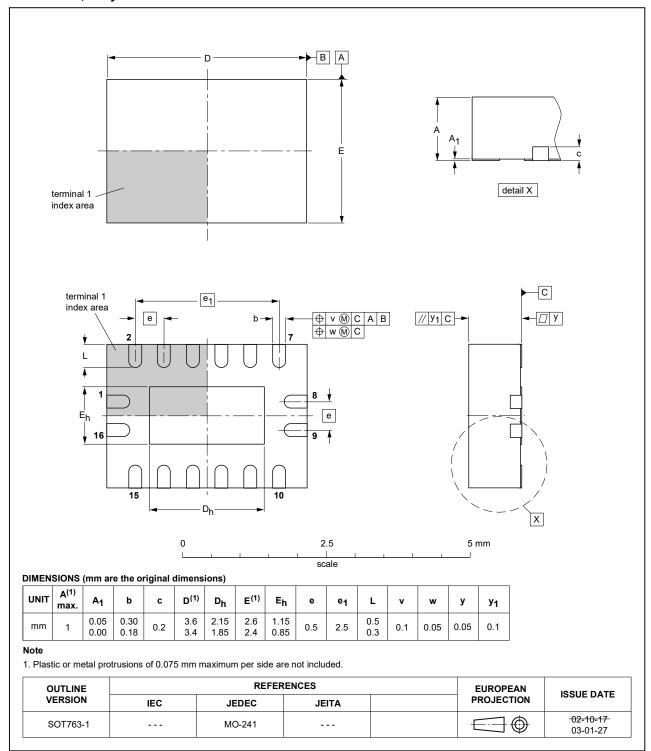


Fig. 16. Package outline SOT763-1 (DHVQFN16)

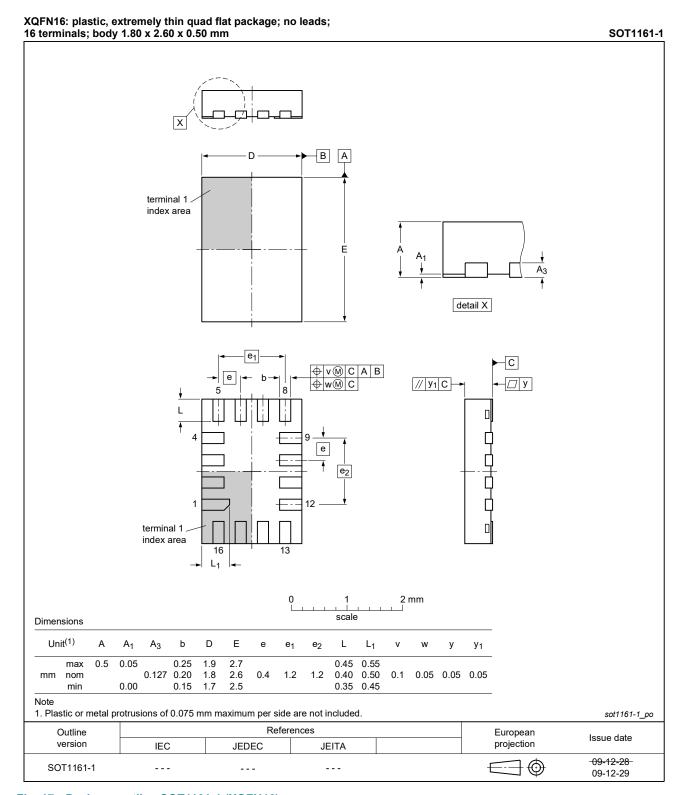


Fig. 17. Package outline SOT1161-1 (XQFN16)

14. Abbreviations

Table 17. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model

15. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes							
74AVC4T245_Q100 v.5	20200317	Product data sheet	-	74AVC4T245_Q100 v.4							
Modifications:	<u>Section 2</u> up	Section 2 updated.									
74AVC4T245_Q100 v.4	20190613	20190613 Product data sheet - 74AVC4T245_Q10									
Modifications:		Type number 74AVC4T245GU-Q100 (SOT1161-1/XQFN16) added. Table 5: Derating values for total power dissipation (Ptot) have changed.									
74AVC4T245_Q100 v.3	20190320	Product data sheet	-	74AVC4T245_Q100 v.2							
Modifications:	guidelines o	f this data sheet has been f Nexperia. nave been adapted to the r	Ū	,							
74AVC4T245_Q100 v.2	20151207	Product data sheet	-	74AVC4T245_Q100 v.1							
Modifications:	• Table 5: con	• <u>Table 5</u> : conditions I _{CC} and I _{GND} changed (errata).									
74AVC4T245_Q100 v.1	20130402	Product data sheet	-	-							

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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